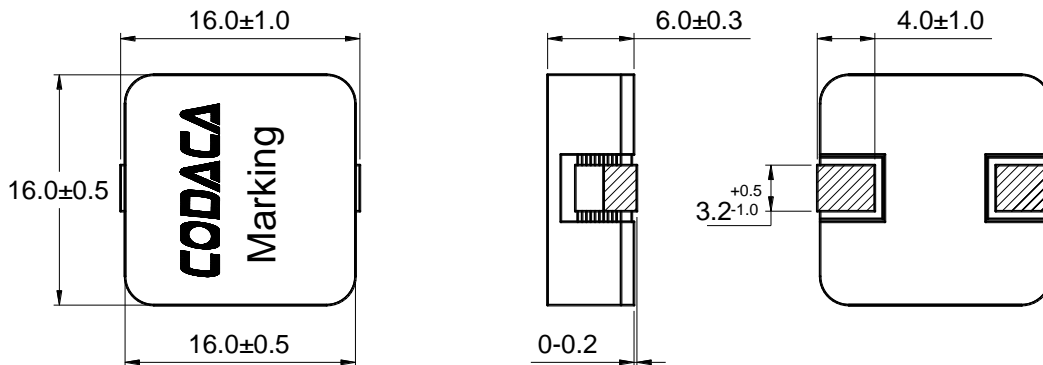


## Outline: 产品概要

- Magnetic shielded structure: excellent resistance to electro magnetic interference(EMI)  
磁屏蔽结构：抗电磁干扰(EMI)性能强
- Flat wire winding, achieve a low D.C. Resistance.  
扁平线绕组，实现极低的直流电阻。
- Low loss, high efficiency, wide application frequency and application scope.  
低损耗，高效率，应用频率宽，适用范围广。
- Lightweight design, save space, suitable for high density SMT.  
轻薄型设计，节省空间，适合高密度贴装。
- Operating temperature :  $-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$   
(Including coil's temperature rise)  
工作温度： $-40^{\circ}\text{C} \sim +125^{\circ}\text{C}$  (包含线圈发热)

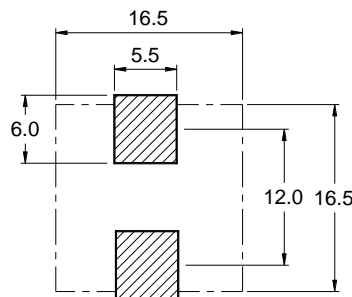
## 1 Appearance and dimensions (mm) 外形尺寸



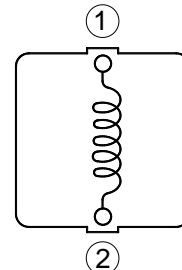
## 2 Marking 印字标识



## 3 Reference land pattern (mm) 参考基板尺寸



## 4 Schematic 原理图



## 5 Electrical characteristics

### 电气特性

Part No. 型号	Inductance (μH) 电感值 ※1 ±20%	D.C.R. (mΩ) 直流电阻		Saturation current (A) 饱和电流 ※2 Typical	Temperature rise current (A) 温升电流 ※3 Typical
		Typical	Max		
CSB1660-R56M	3.30	0.82	1.00	80.0	30.0

■ All data is tested based on 25°C ambient temperature.

所有数据基于环境温度 25°C 条件下测试。

※1 Inductance measure condition at 100kHz, 0.1V.

电感测试条件为 100kHz, 0.1V。

※2 Saturation current: the actual value of DC current when the inductance decrease 30% of its initial value.

饱和电流: 电感值下降其初始值的 30% 时所加载的实际直流电流值。

※3 Temperature rise current: the actual value of DC current when the temperature rise is  $\Delta T 50^{\circ}\text{C}$  ( $T_a=25^{\circ}\text{C}$ ).

温升电流: 使产品温度上升到  $\Delta T 50^{\circ}\text{C}$  时所加载的实际直流电流值 ( $T_a=25^{\circ}\text{C}$ )。

※ Special remind: Circuit design, component placement, PWB size and thickness, cooling system and etc. all will affect the product temperature. Please verify the product temperature in the final application.

特别提醒: 线路设计, 组件布局, 印刷线路板(PWB)尺寸及厚度, 散热系统等均会影响产品温度。

请务必在最终应用时, 验证产品发热状况。

### 6 Saturation current VS temperature rise current curve

饱和电流 VS 温升电流曲线

